



6 Output LVPECL Fanout Buffer

Features

- → 6 differential LVPECL outputs
- → 2 selectable reference inputs support either single-ended or differential
- → Up to 2GHz output frequency
- → Ultra low additive phase jitter: < 0.01 ps (typ) (differential 156.25MHz, 12KHz to 20MHz integration range)
- → Low skew between outputs
- → Low delay from input to output (Tpd typ. < 0.7ns)
- → Separate Input output supply voltage for level shifting
- \rightarrow 2.5V / 3.3V power supply
- → Industrial temperature support
- → Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- → Halogen and Antimony Free. "Green" Device (Note 3)
- → Package: TQFN-32 (ZH)

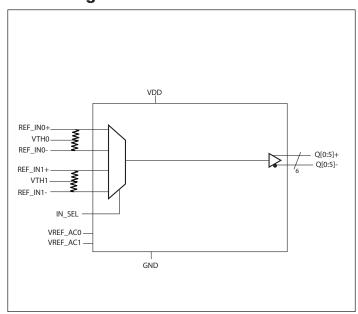
Description

The PI6C5912006 is a high performance LVPECL fanout buffer device which supports up to 2GHz frequency. This device is ideal for systems that need to distribute low jitter LVPECL clock signals to multiple destinations.

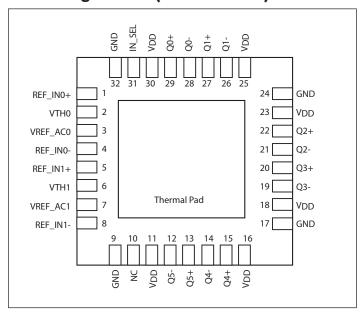
Applications

- → Networking systems including switches and Routers
- → High frequency backplane based computing and telecom platforms

Block Diagram



Pin Configuration (32-Pin TQFN)



Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.





Pin Description

Pin #	Pin Name	Ту	pe	Description		
1,	REF_IN0+	T		D.f		
4	REF_IN0-	in]	out	Reference input 0. Accepts Differential or Single Ended inputs		
2	VTH0	Inj	out	Input Termintaion Center Tap for REF_IN0. Internal 50Ω termination		
3	VREF_AC0	Out	tput	Bias voltage output.		
5,	REF_IN1+	T				
8	REF_IN1-	Inj	out	Reference input 1. Accepts Differential or Single Ended inputs		
6	VTH1	Inj	put	Input Termintaion Center Tap for REF_IN0. Internal 50Ω termination		
7	VREF_AC1	Out	tput	Bias voltage output.		
9, 17, 24, 32	GND	Pov	wer	Power supply ground		
10	NC	-		No Connect		
11, 16, 18, 23, 25, 30	VDD	Pov	wer	Core power supply		
12,	Q5-	0		IMPECIAL SE		
13	Q5+	Out	tput	LVPECL output pair 5.		
14,	Q4-	0		IMPECIAL		
15	Q4+	Out	tput	LVPECL output pair 4.		
19,	Q3-	0		IMPEGI A A 1 2		
20	Q3+	Out	tput	LVPECL output pair 3.		
21,	Q2-	0		IMPEGI A A 1 2		
22	Q2+	Out	tput	LVPECL output pair 2.		
26,	Q1-			TYPECT		
27	Q1+	Output		LVPECL output pair 1.		
28,	Q0-			IMPEGI. A A A A A		
29	Q0+	Out	tput	LVPECL output pair 0.		
31	IN_SEL	Input	Pullup	Input clock select. See Table 1 for function. LVCMOS/LVTTL interface levels.		

Function Table

Table 1: Input select function

IN_SEL Function	
0	REF_IN0 is the selected reference input
1 (default)	REF_IN1 is the selected reference input





Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
C _{IN}	Input Capcitance			2		pF
R _{PULLUP}	Input Pullup Resistor			25		kΩ

Maximum Ratings (Above which the useful life may be impaired. For user guidelines, not tested)

_	
	Storage temperature55 to +150°C
	Supply Voltage to Ground Potential ($V_{DD, V_{DDO}}$)0.5 to +4.6V
	Inputs (Referenced to GND)0.5 to $\rm V_{\rm DD} + 0.5 \rm V$
	Clock Output (Referenced to GND)0.5 to $\rm V_{\scriptscriptstyle DD} + 0.5 \rm V$
	Latch up200mA
	ESD Protection (Input)2000 V min (HBM)
	ESD Protection (Input) 1000 V min (CDM)

Note:

Stresses greater than those listed under MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

Power Supply Characteristics and Operating Conditions

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
V_{DD}	Core Supply Voltage		3.135	3.3	3.465	V
			2.375	2.5	2.625	V
I_{DD}	Core Power Supply Current	All LVPECL outputs unloaded			105	mA
T _A	Ambient Operating Temperature		-40		85	°C

DC Electrical Specifications - Differential Inputs

Symbol	Parameter		Min.	Тур.	Max.	Units
I_{IH}	Input High current	$Input = V_{DD}$			20	uA
I_{IL}	Input Low current	Input = GND	-20			uA
V _{IH}	Input high voltage				V _{DD} +0.3	V
V _{IL}	Input low voltage		-0.3			V
V_{ID}	Input Differential Amplitude PK-PK		0.1			V
V _{CM}	Common model input voltage		GND + 0.5		V _{DD} -0.85	V
ISO _{MUX}	MUX isolation			-89		dBc





DC Electrical Specifications - LVCMOS Inputs

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Units
I_{IH}	Input High current	$Input = V_{DD}$			150	uA
I_{IL}	Input Low current	Input = GND	-150			uA
V_{IH}	Input high voltage	$V_{\rm DD}$ =3.3V	2.0		V _{DD} +0.3	V
V _{IL}	Input low voltage	V _{DD} =3.3V	-0.3		0.8	V
V _{IH}	Input high voltage	V _{DD} =2.5V	1.7		V _{DD} +0.3	V
V _{IL}	Input low voltage	V _{DD} =2.5V	-0.3		0.7	V

DC Electrical Specifications- LVPECL Outputs

Parameter	Description	Conditions	Min.	Тур.	Max.	Units
V _{OH}	Output High voltage		V _{DDO} -1.4		V _{DDO} -0.9	V
Vol	Output Low voltage	V _{DD} =2.5V	V _{DDO} -1.95		V _{DDO} -1.25	V
		V _{DD} =3.3V	V _{DDO} -2.2		V _{DDO} -1.25	V

AC Electrical Specifications – Differential Inputs

Parameter	Description	Conditions	Min.	Тур.	Max.	Units
F _{IN}	Clock input frequency				2000	MHz
V _{INPP}	Differential Input peak to peak voltage	$1.5 \text{GHz} \le F_{IN} \le 2 \text{ GHz}$	0.2		1.5	V
		$F_{IN} \le 1.5 \text{ GHz}$	0.1		1.5	V
ER	Input Edge Rate		1.5			V/ns

AC Electrical Specifications – LVCMOS Inputs

Parameter	Description	Conditions	Min.	Тур.	Max.	Units
F _{IN}	Clock input frequency				200	MHz
V _{INPP}	Differential Input peak to peak voltage	$1.5 \text{GHz} \le F_{IN} \le 2 \text{ GHz}$	0.2		1.5	V
		$F_{IN} \le 1.5 \text{ GHz}$	0.1		1.5	V
ER	Input Edge Rate		1.5			V/ns

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AC Electrical Specifications – LVPECL Outputs

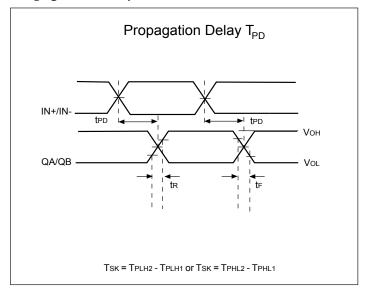
Parameter	Description	Conditions	Min.	Тур.	Max.	Units
F _{OUT}	Clock output frequency	LVPECL			2000	MHz
T _r	Output rise time	From 20% to 80%		150		ps
T _f	Output fall time	From 80% to 20%		150		ps
Todc	Output duty cycle		48		52	%
3.7	Output spring Cingle and d	$1GHz < F_{IN} \le 2 GHz$	0.25		0.85	V
V _{PP}	Output swing Single-ended	$F_{IN} \le 1 \text{ GHz}$	0.5		0.95	V
T	Duffen additive iitten DMC	156.25MHz, 12kHz to 20MHz		0.01		ps
Tj	Buffer additive jitter RMS	156.25MHz, 10kHz to 1MHz		0.01		ps
Tsk	Output Skew			13	30	ps
T_{PD}	Propagation Delay			620	700	ps
T _{OD}	Valid to HiZ				100	ns
T _{OE}	HiZ to valid				100	ns
T _{P2P} Skew	Part to Part Skew ¹		-50		50	ps
V _{REF_AC}	Input bias voltage	$I_{AC} = 2mA$	V _{DD} -1.6		V _{DD} -1.1	V

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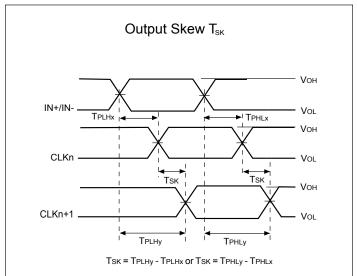




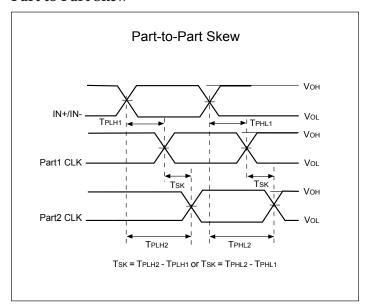
Propagation Delay



Output Skew



Part to Part Skew

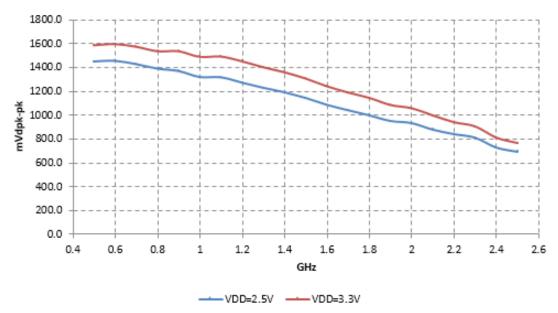


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LVPECL Output Swing vs. Frequency

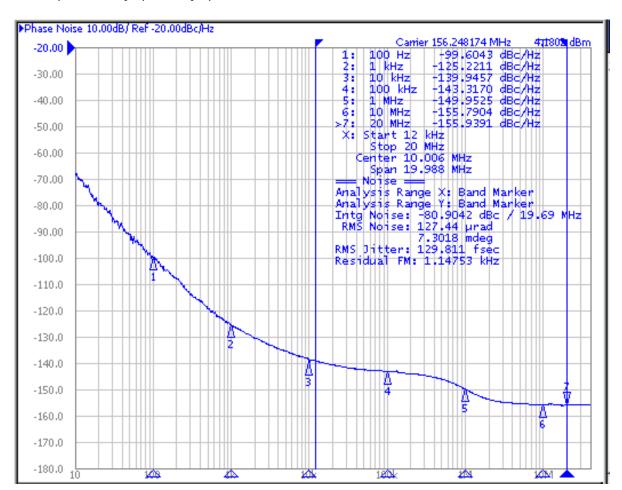




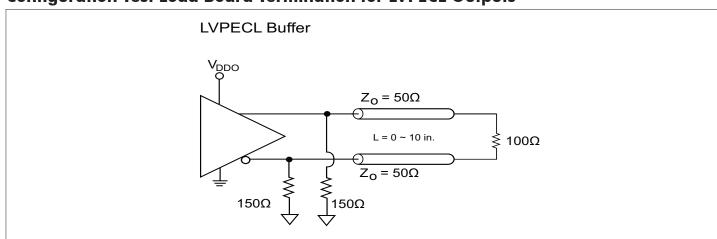


Phase Noise and Additive Jitter

Output phase noise (Dark Blue) vs Input Phase noise (light blue) Additive jitter = $\sqrt{\text{(Output jitter}^2 - Input jitter}^2)}$



Configuration Test Load Board Termination for LVPECL Outputs

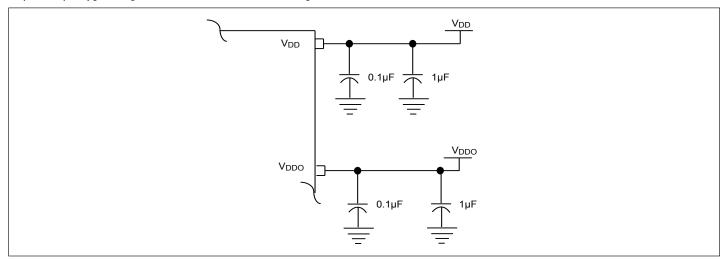






Power Supply Filtering Techniques

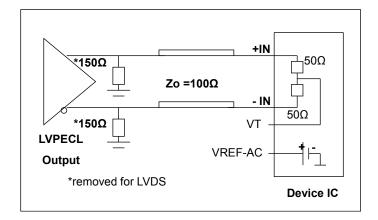
As in any high speed analog circuitry, the power supply pins are vulnerable to random noise. To achieve optimum jitter performance, power supply isolation is required. All power pins should be individually connected to the power supply plane through vias, and $0.1\mu F$ an $1\mu F$ bypass capacitors should be used for each pin.

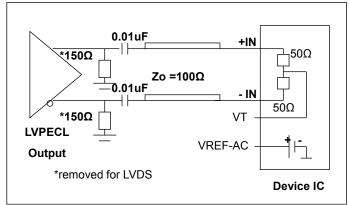


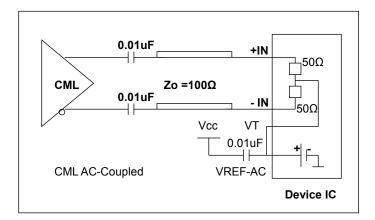


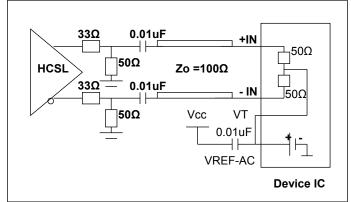


Using Differential Inputs to PI6C5912006









Thermal Information

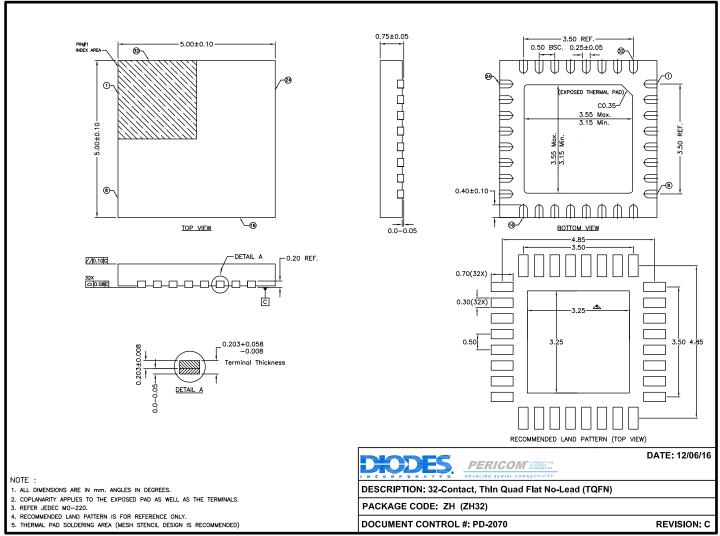
Symbol	Description	Condition	
$\Theta_{_{ m JA}}$	Junction-to-ambient thermal resistance	Still air	44.7 °C/W
$\Theta_{ m JC}$	Junction-to-case thermal resistance		21.7 °C/W

Part Marking





Packaging Mechanical: 32-TQFN (ZH)



17-0570

For latest package info.

please check: http://www.diodes.com/design/support/packaging/pericom-packaging/packaging-mechanicals-and-thermal-characteristics/

Ordering Information

Ordering Code	Package Code	Package Type	Operating Temperature
PI6C5912006ZHIEX	ZH	32-contact, Thin Quad Flat No-Lead (TQFN)	-40 °C to 85 °C

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- $2. \ See \ https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.$
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. E = Pb-free and Green
- 5. X suffix = Tape/Reel





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